

HZ-LL Series

Silicon Planar Zener Diode for Hard Knee Low Noise

REJ03G0183-0300 Rev.3.00 Nov 08, 2007

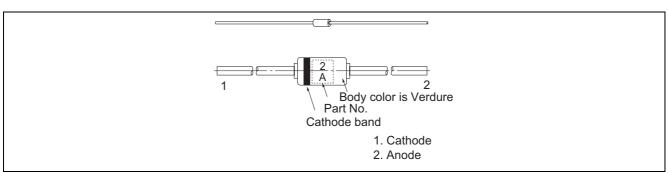
Features

- V_Z - I_Z characteristics are semi logarithmic linear from $I_Z = 1$ nA to 1 mA and have sharper breakdown knees in a low current region, and also lower V_Z temperature coefficients.
- Low dynamic impedance and low noise in the low current region (approximately 1/10 lower than the current zeners).

Ordering Information Ordering Information

Part No.	Cathode Band	Package Name	Package Code	
HZ-LL Series	Navy blue	DO-35	GRZZ0002ZB-A	

Pin Arrangement



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

tem	Symbol	Value	Unit
Power dissipation	Pd	250	mW
Junction temperature	Tj	175	°C
Storage temperature	Tstg	-55 to +175	°C

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

	Zener Voltage		Reverse Current Dynamic Res		esistance		Linearity*3				
	V _z (V) * ¹		I _R (nA) Z _{ZT} (Ω)		_r (Ω)	Z _{ZK} (Ω)* ²		ΔV _{Z1} (V)	$\Delta V_{Z2}(V)$		
Part No.	Min	Max	Iz (mA)	Max	V _R (V)	Max	I _{ZT} (mA)	Тур	I _{zκ} (μA)	Max	Max
HZ2ALL	1.6	2.0	0.5	100	0.5	350	0.5	(1.2)	50	0.5	0.6
HZ2BLL	1.9	2.3									
HZ2CLL	2.2	2.6									
HZ3ALL	2.5	2.9	0.5	100	1.0	360	0.5	(1.2)	50	0.5	0.6
HZ3BLL	2.8	3.2									
HZ3CLL	3.1	3.5									
HZ4ALL	3.4	3.8	0.5	100	2.0	370	0.5	(1.5)	50	0.5	0.6
HZ4BLL	3.7	4.1									
HZ4CLL	4.0	4.4									
HZ5ALL	4.3	4.7	0.5	100	3.0	380	0.5	(1.5)	50	0.5	0.6
HZ5BLL	4.6	5.0									
HZ5CLL	4.9	5.3									

Notes: 1. Tested with DC.

- 2. Reference only.
- 3. $\Delta V_{Z1} = V_Z (I_Z = 0.5 \text{ mA}) V_{Z1} (I_z = 0.05 \text{ mA})$ $\Delta V_{Z2} = V_{Z1} (I_Z = 0.05 \text{ mA}) V_{Z2} (I_z = 0.001 \text{ mA})$

Main Characteristic

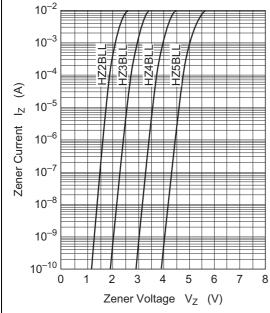
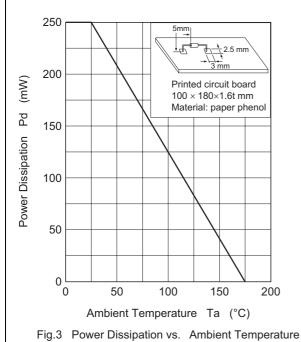


Fig.1 Zener current vs. Zener voltage



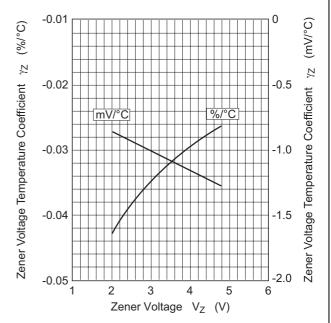
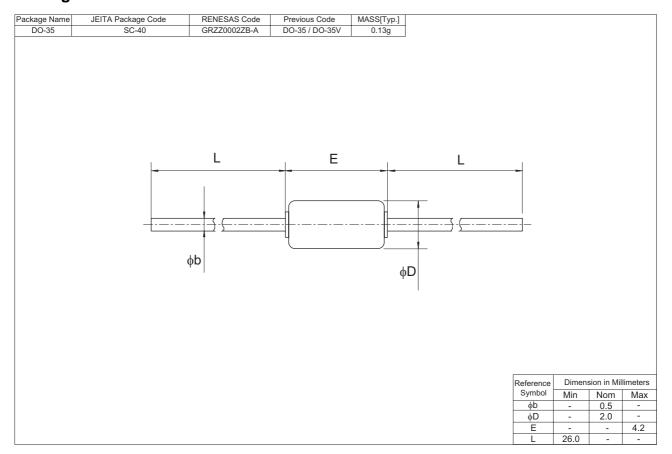


Fig.2 Temperature Coefficient vs. Zener voltage

Package Dimensions



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